NSN 5961-00-290-1880

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View Online at https://aerobasegroup.com/nsn/5961-00-290-1880 **Inclosure Material:** Ceramic **Overall Length:** 0.610 inches **Overall Width:** 0.393 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 9.00 amperes all primaries **Power Rating Per Characteristic:** 117.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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